



## Sheet 5: Frequency Response

- 1) The high-frequency response of an amplifier is characterized by two poles at  $\omega_{p1}$  and  $\omega_{p2}$ . For  $\omega_{p1} = k\omega_{p2}$  find the value of  $k$  that results in the exact value of  $\omega_H$  being  $0.99\omega_{p1}$ .
- 2) A common source amplifier is designed to have a midband voltage gain of  $-29$ , the transistor has  $C_{gs} = 0.5\text{pF}$  and  $C_{gd} = 0.1\text{pF}$ .
  - i. Calculate the latched capacitance at the input and output terminals
  - ii. If the pole at the input terminal is the dominant pole, for what range of source resistances ( $R_s$ ) can  $f_H$  exceed  $10\text{MHz}$
- 3) A common source amplifier has  $C_{gs} = 2\text{pF}$ ,  $C_{gd} = 0.1\text{pF}$ ,  $C_{db} = 0.2\text{pF}$ ,  $C_L = 1.8\text{pF}$ ,  $R_D = 5\text{k}\Omega$  and  $g_m = 4\text{mA/V}$ ,
  - i. Find  $A_M$ ,  $f_H$ , and the gain bandwidth product
  - ii. State whether the unity gain frequency is equal to the gain bandwidth product.
  - iii. If  $R_D$  is changed to be  $20\text{k}\Omega$ , repeat parts (a) and (b).
- 4) A common gate amplifier is specified to have  $C_{gs} = 2\text{pF}$ ,  $C_{gd} = 0.1\text{pF}$ ,  $C_{db} = 0.2\text{pF}$ ,  $C_L = 1.8\text{pF}$ ,  $R_D = 5\text{k}\Omega$  and  $g_m = 4\text{mA/V}$ ,  $R_s = 1\text{k}\Omega$ , and  $R_D = 20\text{k}\Omega$ .
  - i. Find the low-frequency gain ( $A_M$ )
  - ii. Find the frequencies of the poles  $f_{P1}$  and  $f_{P2}$ , and hence an estimation for  $f_H$ .
- 5) Find the midband gain and an estimation of the 3dB frequency of a MOSFET cascode amplifier operated at  $g_m = 1\text{mA/V}$  and  $r_o = 50\text{k}\Omega$ . The MOSFETs have  $C_{gs} = 30\text{fF}$ ,  $C_{gd} = 10\text{fF}$ , and  $C_{db} = C_{sb} = 10\text{fF}$ . The amplifier is fed from a signal source with  $R_s = 100\text{k}\Omega$  and is connected to a load resistance  $R_L = 2\text{M}\Omega$ . There is also a load capacitance  $C_L = 40\text{fF}$ .

- 6) A passive loaded differential amplifier is biased with a current source  $I = 200 \mu A$ . The transistors have  $W/L = 25$ ,  $k'_n = 200 \mu A/V^2$ ,  $V_A = 200 V$ ,  $C_{gs} = 40 fF$ ,  $C_{gd} = 5 fF$ , and  $C_{db} = 5 fF$ . The drain resistors are  $20 k\Omega$  each. Also, there is a  $100 fF$  capacitive load between each drain and ground.
- Find  $V_{ov}$  and  $g_m$  for each transistor.
  - Find the differential gain  $A_d$ .
  - If the frequency response is determined primarily by the output pole, estimate the  $3dB$  frequency.
  - If the current source has  $R_{SS} = 80 k\Omega$  and  $C_{SS} = 0.1 pF$ . Find the  $3dB$  frequency of the  $CMRR$ .
- 7) An active loaded differential amplifier is biased with a current source  $I = 0.2 mA$ . All the transistors are operating at  $|V_{OV}| = 0.2 V$ . The Early voltage for all the transistors is  $|V_A| = 10 V$ . The total capacitance at the input node of the mirror is  $0.1 pF$  and that at the output node of the amplifier is  $0.2 pF$ .
- Find the Midband differential gain  $A_M$
  - Find the frequencies of the poles and the zero of  $A_d(s)$ .